HALOGEN

FREE



## Low-Voltage, Low Ron Quad SPST Analog Switch

### **DESCRIPTION**

The DG2041/2042/2043 are quad single-pole/single-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, fast switching, low on-resistance ( $R_{DS(on)}$ : 1  $\Omega$  at 2.7 V) and small physical size, the DG2041/2042/2043 are ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2041/2042/2043 are built on Vishay Siliconix's new high density low voltage process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

#### **FEATURES**

- Low Voltage Operation (1.8 V to 5.5 V)
- Low On-Resistance  $R_{DS(on)}$ : 1  $\Omega$
- Fast Switching 14 ns toN
- Low Charge Injection Q<sub>IN.I</sub>: 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- TSSOP-16 and QFN-16 Packages
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

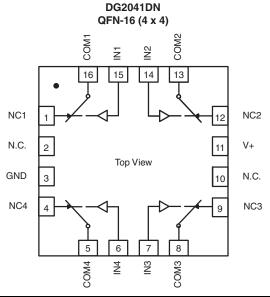
#### BENEFITS

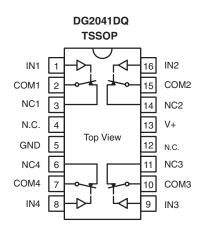
- **Reduced Power Consumption**
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

### **APPLICATIONS**

- Cellular Phones
- Communication Systems
- Portable Test Equipment
- **Battery Operated Systems**
- Sample and Hold Circuits

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION - DG2041



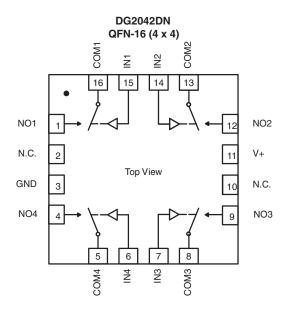


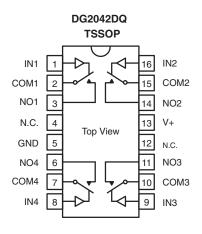
TRUTH TABLE - DG2041	
Logic	Switch
0	On
1	Off

Switches Shown for Logic "0" Input



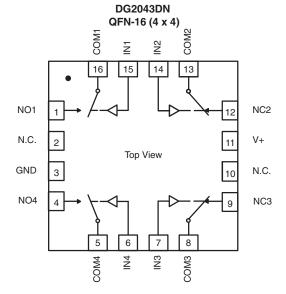
### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION - DG2042, DG2043

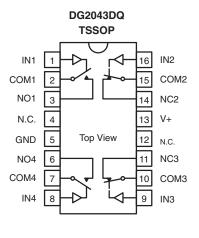




TRUTH TABLE - DG2042	
Logic	Switch
0	Off
1	On

Switches Shown for Logic "0" Input





TRUTH TABLE - DG2043		
Logic	Switches 1, 4	Switches 2, 3
0	Off	On
1	On	Off

Switches Shown for Logic"0" Input



ORDERING INFORMATION									
Temp Range	Package	Part Number							
		DG2041DQ-T1							
		DG2041DQ-T1-E3							
	TSSOP-16	DG2042DQ-T1							
	1330F-16	DG2042DQ-T1-E3							
- 40 °C to 85 °C		DG2043DQ-T1							
		DG2043DQ-T1-E3							
	OFN 40 (4 mm - 4 mm)	DG2041DN-T1-E4							
	QFN-16 (4 mm x 4 mm) (Variation 1)	DG2042DN-T1-E4							
	(vanadon 1)	DG2043DN-T1-E4							

ABSOLUTE MAXIMUM RATINGS										
Parameter		Symbol	Limit	Unit						
Reference V+ to GND			- 0.3 to + 6	V						
IN, COM, NC, NO <sup>a</sup>			- 0.3 to (V+ + 0.3)	v						
Continuous Current (Any terminal)			± 50	mA						
Peak Current (Pulsed at 1 ms, 10 % d	uty cycle)		± 200	IIIA						
Storage Temperature (D Suffix)			- 65 to 150	°C						
Develop Dissipation (Deales as)	TSSOP-16 <sup>c</sup>		450	mW						
Power Dissipation (Packages) <sup>b</sup>	QFN-16 (4 mm x 4 mm) <sup>d</sup>		1880	11100						

#### Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 5.6 mW/°C above 70 °C
- d. Derate 23.5 mW/°C above 70 °C
- e. Manual soldering with soldering iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS (V+ = 2 V)										
		Test Conditions Otherwise Unless Specified		- 40	Limits 0 °C to 85	5 °C				
Parameter	Symbol	$V+ = 2 V$ , $V_{IN} = 0.4 V$ or 1.6 $V^e$	Temp.a	Min.b	Typ.c	Max.b	Unit			
Analog Switch										
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC} V_{COM}$		Full	0		V+	V			
On- Resistance	R <sub>ON</sub>	V+ = 2 V, V <sub>COM</sub> = 0.2 V/1.2 V, I <sub>NO</sub> , I <sub>NC</sub> = 10 mA	Room Full		3	6.3 6.3				
R <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	$V+ = 2 V$ , $V_{COM} = 0 V$ to $V+$ , $I_{NO}$ , $I_{NC} = 10 \text{ mA}$	Room			4.2	Ω			
R <sub>ON</sub> Match Between Channels	$\Delta R_{ON}$		Room			0.4				
Outtob Off Looks as Ourself	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 2.2 V	Room Full <sup>d</sup>	- 1 - 10		1 10				
Switch Off Leakage Current <sup>r</sup>	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC} = 0.2 \text{ V/2 V}$ , $V_{COM} = 2 \text{ V/0.2 V}$	Room Full <sup>d</sup>	- 1 - 10		1 10	nA			
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 2.2 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.2 \text{ V/2 V}$	Room Full <sup>d</sup>	- 1 - 10		1 10				

# DG2041, DG2042, DG2043

# Vishay Siliconix



SPECIFICATIONS (V	′+ = 2 V)						
		Test Conditions Otherwise Unless Specified		<b>Limits</b> - 40 °C to 85 °C			
Parameter	eter Symbol $V+ = 2 \text{ V}, V_{IN} = 0.4 \text{ V} \text{ or } 1.6 \text{ V}^e$					Max.b	Unit
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.6			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	V
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		4		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 V or V+	Full	- 1		1	μΑ
Dynamic Characteristics			•				
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room Full <sup>d</sup>		30	81 82	
Turn-Off Time	t <sub>OFF</sub>	fig. 1 and 2	Room Full <sup>d</sup>		22	41 42	ns
Break-Before-Make Time Delay	t <sub>D</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF (DG2043 Only)	Room	5			
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega, \text{ fig. 2}$	Room		1		рC
Off-Isolation <sup>d</sup>	OIRR	D 5000 5 7 1 1 MIL-	Room		- 63		j
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 95		dB
NO, NC Off Capacitance <sup>d</sup>	$C_{NO(off)} \ C_{NC(off)}$	V <sub>IN</sub> = 0 V or V+, f = 1 MHz	Room		24		pF
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>		Room		48		-
Power Supply	•		•		•		
Power Supply Current <sup>d</sup>	l+	V <sub>IN</sub> = 0 V or V+			0.001	1	μΑ

SPECIFICATIONS (V+ = 3 V)										
		Test Conditions Otherwise Unless Specified	d			<b>Limits</b> - 40 to 85 °C				
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.4 V \text{ or } 2 V^{e}$	Temp.a	Min.b	Typ. <sup>c</sup>	Max.b	Unit			
Analog Switch										
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC}$ $V_{COM}$		Full	0		V+	٧			
On-Resistance	R <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 0.7 \text{ V}/1.5 \text{ V}, I_{NO},$ $I_{NC} = 10 \text{ mA}$	Room Full		1.6	2.1 2.2				
R <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	V+ = 2.7 V, V <sub>COM</sub> = 0 V to V+, I <sub>NO</sub> , I <sub>NC</sub> = 10 mA				0.7	Ω			
R <sub>ON</sub> Match Between Channels	$\Delta R_{ON}$		Room			0.3				
Switch Off Leakage Current <sup>f</sup>	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 3.3 V	Room Full	- 1 - 10		1 10				
Owner on Leakage ourrent	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC} = 0.3 \text{ V/3 V}$ , $V_{COM} = 3 \text{ V/0.3 V}$	Room Full	- 1 - 10		1 10	nA			
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V/3 V}$	Room Full	- 1 - 10		1 10				
Digital Control										
Input High Voltage <sup>d</sup> V <sub>I</sub>			Full	1.6			V			
Input Low Voltage	V <sub>INL</sub>		Full			0.4	, v			
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		4		pF			
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 V or V+	Full	- 1		1	μΑ			



SPECIFICATIONS (V+ = 3 V)									
		Test Conditions Otherwise Unless Specified		- 40	Limits - 40 °C to 85 °C				
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.4 V \text{ or } 2 V^{e}$	Temp.a	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit		
Dynamic Characteristics									
Turn-On Time <sup>d</sup>	$t_{ON}$	$V_{NO}$ or $V_{NC} = 2 \text{ V}$ , $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room Full		19	51 52			
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	fig. 1 and 2	Room Full		17	36 37	ns		
Break-Before-Make Time Delay	t <sub>D</sub>	$V_{NO}$ or $V_{NC}$ = 2 V, $R_{L}$ = 300 $\Omega$ , $C_{L}$ = 35 pF (DG2043 Only)	Room	2					
Charge Injection <sup>d</sup>	$Q_{INJ}$	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ $\Omega$ , fig. 2	Room		3		рC		
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 1 MHz$	Room		- 63		dB		
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	11[ = 30 32, 0[ = 3 μι, τ = 1 ινιτι2	Room		- 94		ub		
NO, NC Off Capacitance <sup>d</sup>	$C_{NO(off)} \ C_{NC(off)}$	V <sub>IN</sub> = 0 V or V+, f = 1 MHz	Room		25		pF		
Channel-On Capacitance <sup>d</sup> Con			Room		49				
Power Supply									
Power Supply Current	l+	$V_{IN} = 0 V \text{ or } V+$			0.001	1	μΑ		

SPECIFICATIONS (V+ = 5 V)										
		Test Conditions Otherwise Unless Specified		- 40						
Parameter	Symbol	$V+ = 5 V$ , $\pm 10 \%$ , $V_{IN} = 0.8 V$ or 2.4 $V^e$	Temp.a	Min.b	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit			
Analog Switch										
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC} \ V_{COM}$		Full	0		V+	V			
On-Resistance	$R_{ON}$	$V+ = 4.5 \text{ V}, V_{COM} = 0.7 \text{ V}/2.5 \text{ V}, I_{NO},$ $I_{NC} = 10 \text{ mA}$	Room Full		1	1.5 1.6				
R <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	$V+ = 4.5 \text{ V}, V_{COM} = 0 \text{ V to V}+, I_{NO}, I_{NC} = 10 \text{ mA}$	Room			0.7	Ω			
R <sub>ON</sub> Match Between Channels	$\Delta R_{ON}$	V+ = 4.5 V, VCOM = 0 V to V+, INO, INC = 10 IIIA	Room			0.3				
Switch Off Leakage Current	$I_{NO(off)}$ $I_{NC(off)}$	V+ = 5.5 V	Room Full	- 1 - 10		1 10				
Owner on Lounage out on	I <sub>COM(off)</sub>	V <sub>NO</sub> , V <sub>NC</sub> = 1 V/4.5 V, V <sub>COM</sub> = 4.5 V/1 V	Room Full	- 1 - 10		1 10	nA			
Channel-On Leakage Current	I <sub>COM(on)</sub>	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V}/4.5 \text{ V}$	Room Full	- 1 - 10		1 10				
Digital Control										
Input High Voltage	$V_{INH}$		Full	2.4			V			
Input Low Voltage	V <sub>INL</sub>		Full			0.8				
Input Capacitance	C <sub>in</sub>		Full		4		pF			
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 V or V+	Full	- 1		1	μΑ			



SPECIFICATIONS (V+ = 5 V)										
		Test Conditions Otherwise Unless Specified		- 40	Limits - 40 °C to 85 °C					
Parameter	Symbol	$V+ = 5 V$ , $\pm 10 \%$ , $V_{IN} = 0.8 V$ or 2.4 $V^e$	Temp.a	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit			
Dynamic Characteristics										
Turn-On Time <sup>d</sup>	t <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ = 3 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room Full		13	42 43				
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	fig. 1 and 2	Room Full		19	32 33	ns			
Break-Before-Make Time Delay	t <sub>D</sub>	$V_{NO}$ or $V_{NC}$ = 3 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF (DG2043 Only)	Room	1						
Charge Injection <sup>d</sup>	$Q_{INJ}$	$C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 $\Omega$ , fig. 2	Room		3		рС			
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 1 MHz$	Room		- 63		dB			
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$11_{1} = 30.52, 0_{1} = 3.61, 1 = 1.101112$	Room		- 93		ub			
Source-Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>	V <sub>IN</sub> = 0 V or V+, f = 1 MHz	Room		26		pF			
Channel-On Capacitance <sup>d</sup> C <sub>ON</sub>			Room		49					
Power Supply										
Power Supply Current	l+	$V_{IN} = 0 V \text{ or } V+$			0.001	1	μΑ			

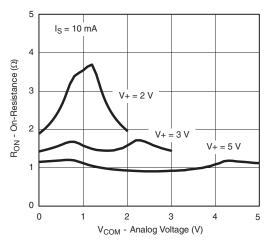
#### Notes:

- a. Room = 25 °C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.

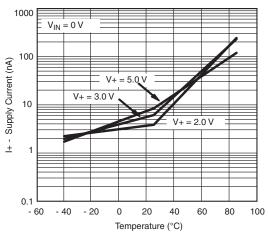
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



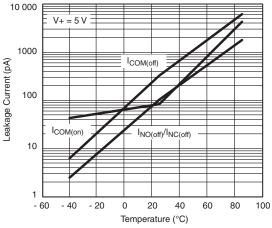
### TYPICAL CHARACTERISTICS (25 °C unless noted)



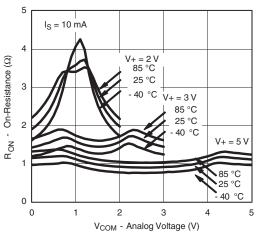
 $R_{ON}$  vs.  $V_{COM}$  and Supply Voltage



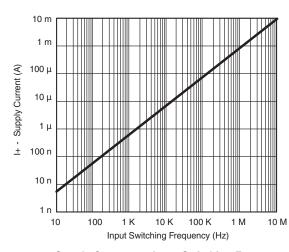
Supply Current vs. Temperature



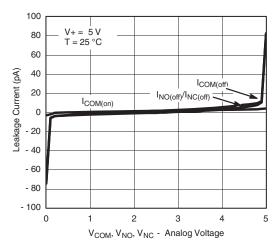
Leakage Current vs. Temperature



R<sub>ON</sub> vs. Analog Voltage and Temperature



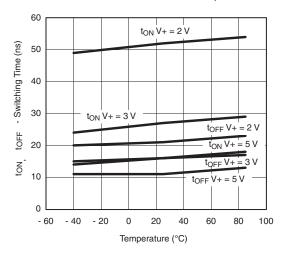
**Supply Current vs. Input Switching Frequency** 



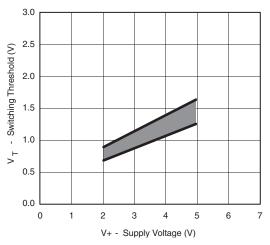
Leakage vs. Analog Voltage

## TYPICAL CHARACTERISTICS (25 °C unless noted)

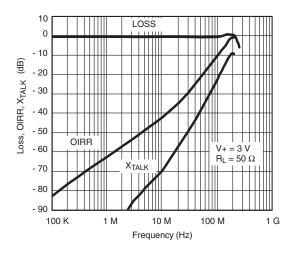




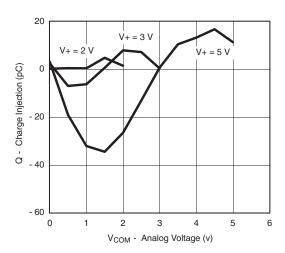
Switching Time vs. Temperature and Supply Voltage



Switching Threshold vs. Supply Voltage



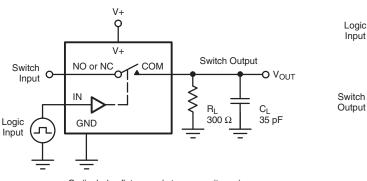
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage

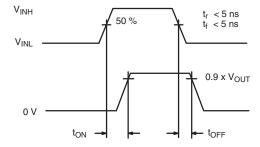


### **TEST CIRCUITS**



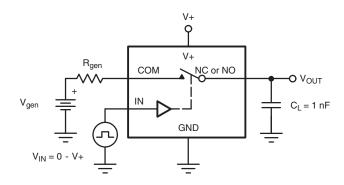
C<sub>L</sub> (includes fixture and stray capacitance)

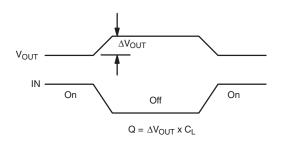
$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

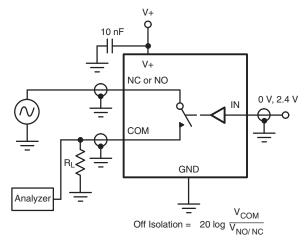
Figure 1. Switching Time

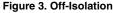




IN depends on switch configuration: input polarity determined by sense of switch.

Figure 2. Charge Injection





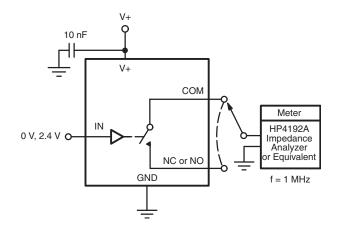
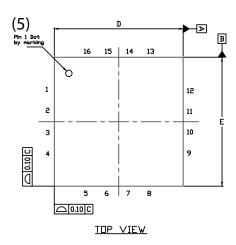


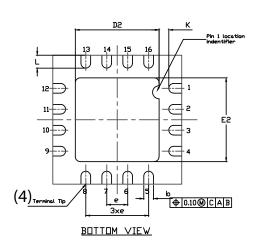
Figure 4. Channel Off/On Capacitance

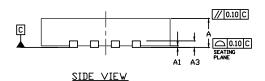
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72091.



### QFN 4x4-16L Case Outline







	VARIATION 1					VARIA	ATION 2					
DIM	МІ	ILLIMETERS <sup>(1)</sup>		INCHES		MILLIMETERS <sup>(1)</sup>		S <sup>(1)</sup>		INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
A3		0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.	
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.010 0.012 0.0	
D		4.00 BSC		0.157 BSC		4.00 BSC			0.157 BSC			
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
е		0.65 BS0			0.026 BSC		0.65 BSC				0.026 BSC	
Е		4.00 BS0			0.157 BSC		4.00 BSC				0.157 BSC	
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
K		0.20 min.			0.008 min.			0.20 min.			0.008 min.	
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.012 0.016 0.020	
N <sup>(3)</sup>		16	16		16		16		16			
Nd <sup>(3)</sup>	4				4		4			4		
Ne <sup>(3)</sup>		4			4			4 4				

#### **Notes**

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

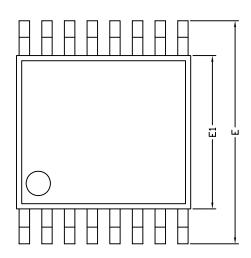
ECN: S13-0893-Rev. B, 22-Apr-13

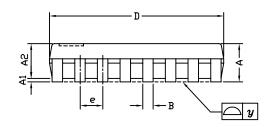
DWG: 5890

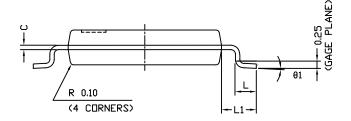
Revision: 22-Apr-13



**TSSOP: 16-LEAD** 







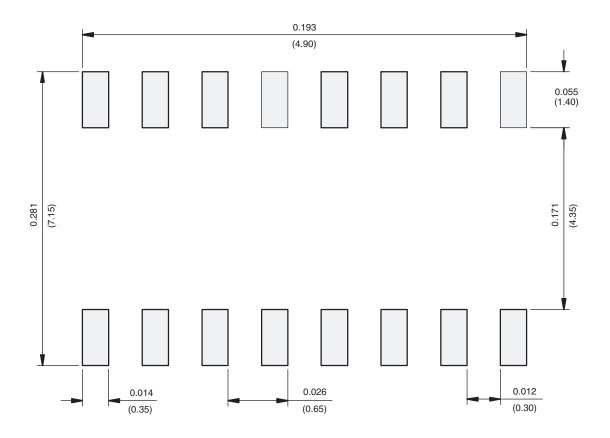
Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
А	=	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>	

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



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